

**isc Silicon PNP Power Transistor**
**2SB1063**
**DESCRIPTION**

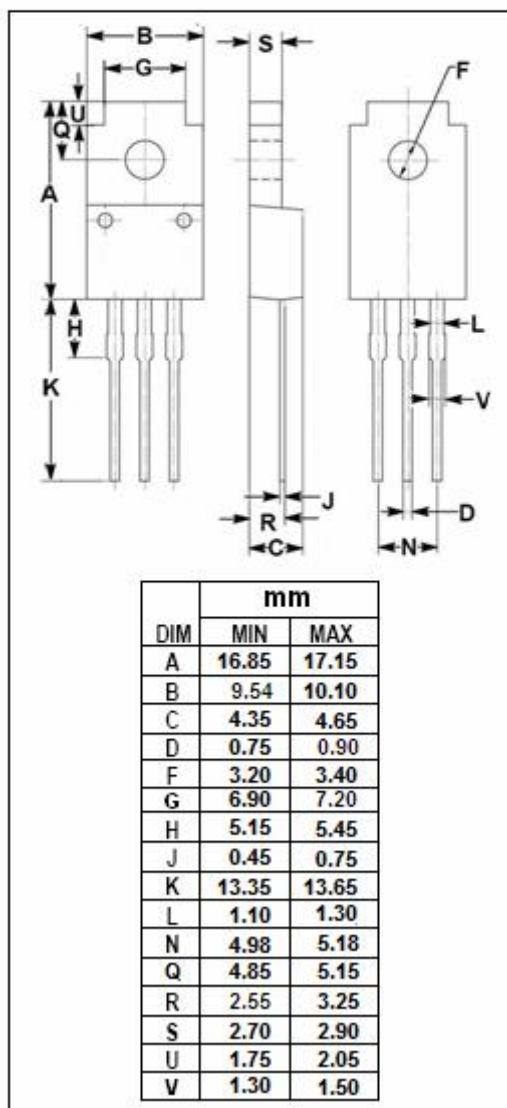
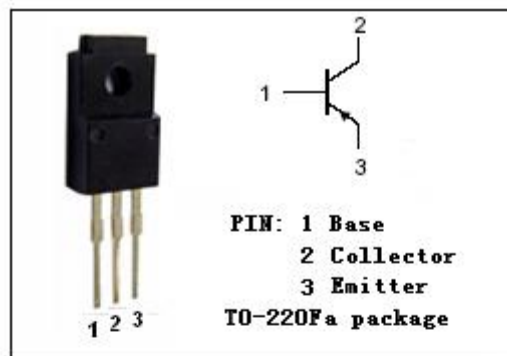
- Low Collector Saturation Voltage-  
:  $V_{CE(sat)} = -2.0V(\text{Max}) @ I_C = -3A$
- Good Linearity of  $h_{FE}$
- Wide Area of Safe Operation
- Complement to Type 2SD1499
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for high power amplification.

**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-100	V
$V_{CEO}$	Collector-Emitter Voltage	-100	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current-Continuous	-5	A
$I_{CM}$	Collector Current-Peak	-8	A
$P_C$	Collector Power Dissipation @ $T_a = 25^\circ\text{C}$	2	W
	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	40	
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**isc Silicon PNP Power Transistor****2SB1063****ELECTRICAL CHARACTERISTICS**T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V			-1.8	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -100V; I <sub>E</sub> = 0			-50	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -3V; I <sub>C</sub> = 0			-50	μ A
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -20mA; V <sub>CE</sub> = -5V	20			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	40		200	
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V	20			
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f= 1MHz		170		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = -0.5A; V <sub>CE</sub> = -5V; f <sub>test</sub> =1MHz		20		MHz

◆ **h<sub>FE-2</sub> Classifications**

R	Q	P
40-80	60-120	100-200

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